



Order

Now







SLOS358C - SEPTEMBER 2011 - REVISED APRIL 2020

Ultra Low Power, Rail-to-Rail Output, Fully-Differential Amplifier

Features

- Ultra Low Power:
 - Voltage: 2.5 V to 5.5 V
 - Current: 250 μA
 - Power-Down Mode: 0.5 µA (typical)
- **Fully-Differential Architecture**
- Bandwidth: 36 MHz
- Slew Rate: 200 V/µs
- THD: -120 dBc at 1 kHz (1 V_{RMS}, R_L = 2 k Ω)
- Input Voltage Noise: 10 nV/ \sqrt{Hz} (f = 1 kHz)
- High DC Accuracy:
 - V_{OS} Drift: ±4 µV/°C (-40°C to +125°C)
 - A_{OL}: 114 dB
- Rail-to-Rail Output (RRO)
- Negative Rail Input (NRI)
- Output Common-Mode Control

Applications 2

- Low-Power SAR, $\Delta\Sigma$ ADC Driver
- Low Power, High Performance:
 - Differential to Differential Amplifier
 - Single-Ended to Differential Amplifier
- Low-Power, Wide-Bandwidth Differential Driver
- Low-Power, Wide-Bandwidth Differential Signal Conditioning
- High Channel Count and Power Dense Systems

Figure 1. 1 kHz FFT Plot on Audio Analyzer

0 -10 $V_s = 5 V$ G = 1 V/V-20 Vout = 1 V_{RMS} -30 $R_F = 2 k\Omega$ -40 Aagnitude (dBV) $R_L = 600 \Omega$ -50 -60 -70 -80 -90 -100 -110 -120 -130 -140 5k 10k 15k 20k 24k Frequency (Hz) G071

3 Description

The THS4531 is a low-power, fully-differential op amp with input common-mode range below the negative rail and rail-to-rail output. The device is designed for low-power data acquisition systems and high density applications where power consumption and dissipation is critical.

The device features accurate output common-mode control that allows for dc coupling when driving analog-to-digital converters (ADCs). This control, coupled with the input common-mode range below the negative rail and rail-to-rail output, allows for easy interface from single-ended ground-referenced signal successive-approximation sources to registers (SARs), and delta-sigma ($\Delta\Sigma$) ADCs using only single-supply 2.5 V to 5 V power. The THS4531 is also a valuable tool for general-purpose, low-power differential signal conditioning applications.

The THS4531 is characterized for operation over the extended industrial temperature range from -40°C to +125°C. The following package options are available:

Device Information⁽¹⁾

DEVICE NUMBER	PACKAGE	BODY SIZE (NOM)
	SOIC (8)	4.90 mm × 3.91 mm
THS4531	VSSOP (8)	3.00 mm × 3.00 mm
	WQFN (10)	2.00 mm × 2.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Table 1. Device Comparison

DEVICE	BW (MHz)	l _Q (mA)	THD (dBc) at 100 kHz	V <u>N</u> (nV/√Hz)	RAIL-TO- RAIL
THS4521	145	1.14	-120	4.6	-In/Out
THS4121	100	16	-79	5.4	In/Out
THS4131	150	16	-107	1.3	No
THS4561	60	0.78	-116	4	-In/Out
THS4551	150	1.37	-128	3.3	-In/Out
THS4541	850	10.1	-137	2.2	-In/Out



Page

Page

Table of Contents

1	Fea	tures	1
2	Арр	lications	1
3	Des	cription	1
4	Rev	ision History	2
5		ctrical Specifications	
	5.1	Absolute Maximum Ratings	4
	5.2	Thermal Information	4
	5.3	Electrical Characteristics: V _S = 2.7 V	5
	5.4	Electrical Characteristics: V _S = 5 V	
6	Dev	ice Information	11
	6.1	PIN Configurations	11
	6.2	Table of Graphs	
7	Тур	ical Characteristics: VS = 2.7 V	13
8		ical Characteristics: VS = 5 V	
9		lication Information	

	9.1	Typical Characteristics Test Circuits	. 25
	9.2	Application Circuits	. 30
	9.3	Audio ADC Driver Performance: THS4531 AND PCM4204 Combined Performance	. 36
	9.4	SAR ADC Performance	38
	9.5	EVM and Layout Recommendations	41
10	Dev	ice and Documentation Support	42
	10.1	Device Support	42
	10.2	Documentation Support	42
	10.3	Community Resources	42
	10.4		
	10.5	Electrostatic Discharge Caution	. 42
	10.6	Glossary	42
11		hanical, Packaging, and Orderable mation	42

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (March 2012) to Revision C

Changes from Revision A (January 2012) to Revision B

•	Deleted DC Performance, <i>Input-referred offset voltage</i> parameter typical specifications for $T_A = 0^{\circ}C$ to +70°C, -40°C to +85°C, and -40°C to +125°C in 2.7 V Electrical Characteristics table	. 6
•	Changed DC Performance, <i>Input-referred offset voltage</i> parameter maximum specifications for $T_A = 0^{\circ}C$ to +70°C, -40°C to +85°C, and -40°C to +125°C in 2.7 V Electrical Characteristics table	. 6
•	Changed DC Performance, <i>Input offset voltage drift</i> parameter typical and maximum specifications in 2.7 V Electrical Characteristics table	. 6
•	Deleted DC Performance, <i>Input bias current</i> parameter typical specifications for $T_A = 0^{\circ}C$ to +70°C, -40°C to +85°C, and -40°C to +125°C in 2.7 V Electrical Characteristics table	. 6
•	Deleted DC Performance, Input bias current drift parameter typical specifications in 2.7 V Electrical Characteristics table	9 <mark>6</mark>
•	Deleted DC Performance, <i>Input offset current</i> parameter typical specifications for $T_A = 0^{\circ}C$ to +70°C, -40°C to +85°C, and -40°C to +125°C in 2.7 V Electrical Characteristics table	. 6
•	Deleted DC Performance, <i>Input-referred offset voltage</i> parameter typical specifications for $T_A = 0^{\circ}C$ to +70°C, -40°C to +85°C, and -40°C to +125°C in 5 V Electrical Characteristics table	. 9
•	Changed DC Performance, <i>Input-referred offset voltage</i> parameter maximum specifications for $T_A = 0^{\circ}C$ to +70°C, -40°C to +85°C, and -40°C to +125°C in 5 V Electrical Characteristics table	. 9
•	Changed DC Performance, Input offset voltage drift parameter typical specifications in 5 V Electrical Characteristics table	. 9
•	Deleted DC Performance, <i>Input bias current</i> parameter typical specifications for $T_A = 0^{\circ}C$ to $+70^{\circ}C,-40^{\circ}C$ to $+85^{\circ}C$, and $-40^{\circ}C$ to $+125^{\circ}C$ in 5 V Electrical Characteristics table	. 9
•	Deleted DC Performance, <i>Input offset current</i> parameter typical specifications for $T_A = 0^{\circ}C$ to +70°C, -40°C to +85°C, and -40°C to +125°C in 5 V Electrical Characteristics table	. 9



Page

Changes from Original (September 2011) to Revision A

Changed status from product preview to production data.....

PRODUCT CHANNEL P		TEMPERATURE		COUNT LEAD DESIGNATOR TEMPERATURE MARKING NUMBER		ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY			
	1	SOIC-8	D	D -40°C to +125°C	T4531	THS4531ID	Rails, 75			
	1	3010-8	D		T4531	THS4531IDR	Tape and reel, 2500			
THS4531		4531	THS4531IDGK	Rails, 80						
1104531	1	VSSOP-8	DGK	-40 C 10 +125 C	–40°C to +125°C	4531	THS4531IDGKR	Tape and reel, 2500		
-	1	WQFN-10	RUN	–40°C to +125°C	4531	THS4531IRUNT	Tape and reel, 250			
	1		RUN	-40 0 10 +125 0	4531	THS4531IRUNR	Tape and reel, 3000			

 Table 2. Packaging and Ordering Information⁽¹⁾

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

5 Electrical Specifications

5.1 Absolute Maximum Ratings

		VALUE	UNITS
Supply voltage, V _S	μ- to V _{S+}	5.5	
Input/output voltag	/output voltage, $V_{IN\pm}$, $V_{OUT\pm}$, and V_{OCM} pins $(V_{S-}) - 0.7$ to $(V_{S+}) + 0.7$		V
Differential input vo	bltage, V _{ID}	1	V
Continuous output	current, I _O	50	mA
Continuous input o	current, l _i	10	mA
Continuous power	dissipation	See Thermal Information)
Maximum junction temperature, T _J 150		°C	
Operating free-air	temperature range, T _A	-40 to +125	°C
Storage temperatu	re range, T _{stg}	-65 to +150	°C
Electrostatic	Human body model (HBM)	del (HBM) 3000	
discharge (ESD)	Charge device model (CDM)	500	V
ratings:	Machine model (MM)	200	V

5.2 Thermal Information

		THS4531	THS4531	THS4531	
	THERMAL METRIC ⁽¹⁾	SOIC (P)	VSSOP (MSOP) (DGK)	WQFN (RUN)	UNITS
		8 PINS	8 PINS	10 PINS	
θ_{JA}	Junction-to-ambient thermal resistance	133	198	163	
θ_{JCtop}	Junction-to-case (top) thermal resistance	78	84	66	
θ_{JB}	Junction-to-board thermal resistance	73	120	113	°C/W
ΨJT	Junction-to-top characterization parameter	26	19	17	°C/VV
Ψјв	Junction-to-board characterization parameter	73	118	113	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report (SPRA953).



5.3 Electrical Characteristics: V_s = 2.7 V

Test conditions at $T_A = 25^{\circ}$ C, $V_{S+} = 2.7$ V, $V_{S-} = 0$ V, $V_{OCM} =$ open, $V_{OUT} = 2$ V_{PP} , $R_F = 2$ k Ω , $R_L = 2$ k Ω differential, G = 1 V/V, single-ended input, differential output, and input and output referenced to mid-supply, unless otherwise noted.

PARAMETER	CONDITIONS	MIN TYP	МАХ	UNITS	TEST LEVEL ⁽¹⁾
AC PERFORMANCE					
	V _{OUT} = 100 mV _{PP} , G = 1	34			
	V _{OUT} = 100 mV _{PP} , G = 2	16		N 41 1-	
Small-signal bandwidth	V _{OUT} = 100 mV _{PP} , G = 5	6		MHz	
	V _{OUT} = 100 mV _{PP} , G = 10	2.7			
Gain-bandwidth product	V _{OUT} = 100 mV _{PP} , G = 10	27		MHz	
Large-signal bandwidth	$V_{OUT} = 2 V_{PP}, G = 1$	34		MHz	
Bandwidth for 0.1-dB flatness	$V_{OUT} = 2 V_{PP}, G = 1$	12		MHz	
Slew rate, rise/fall, 25% to 75%		190/320		V/µs	
Rise/fall time, 10% to 90%	T.	5.2/6.1		ns	
Settling time to 1%, rise and fall		25/20			
Settling time to 0.1%, rise and fall	V _{OUT} = 2 V step	60/60	60/60 ns 150/110 ns		
Settling time to 0.01%, rise and fall	T.	150/110			
Overshoot/undershoot, rise and fall	*	1/1		%	
	f = 1 kHz, V _{OUT} = 1 V _{RMS}	-122			С
2nd-order harmonic distortion	f = 10 kHz	-127		dBc	
	f = 1 MHz	-59			
	f = 1 kHz, V _{OUT} = 1 V _{RMS}	-130			
3rd-order harmonic distortion	f = 10 kHz	-135		dBc	
	f = 1 MHz	-70			
2nd-order intermodulation distortion	f = 1 MHz, 200 Hz tone spacing,	-83		dBc	
3rd-order intermodulation distortion	V _{OUT} envelope = 1 V _{PP}	-81			
Input voltage noise	f = 1 kHz	10		nV/√ Hz	
Voltage noise 1/f corner frequency		45		Hz	
Input current noise	f = 100 kHz	0.25		pA/√Hz	
Current noise 1/f corner frequency		6.5		kHz	
Overdrive recovery time	Overdrive = 0.5 V	65		ns	
Output balance error	V _{OUT} = 100 mV, f = 1 MHz	-65		dB	
Closed-loop output impedance	f = 1 MHz (differential)	2.5		Ω	

(1) Test levels (all values set by characterization and simulation): (A) 100% tested at +25°C; over temperature limits by characterization and simulation. (B) Not tested in production; limits set by characterization and simulation. (C) Typical value only for information.

Electrical Characteristics: V_s = 2.7 V (continued)

Test conditions at $T_A = 25^{\circ}$ C, $V_{S+} = 2.7$ V, $V_{S-} = 0$ V, $V_{OCM} =$ open, $V_{OUT} = 2$ V_{PP} , $R_F = 2$ k Ω , $R_L = 2$ k Ω differential, G = 1 V/V, single-ended input, differential output, and input and output referenced to mid-supply, unless otherwise noted.

PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNITS	TEST LEVEL ⁽¹⁾
DC PERFORMANCE						
Open-loop voltage gain (A _{OL})		100	113		dB	А
	$T_A = +25^{\circ}C$		±200	±1000		А
land the second offerst welter as	$T_A = 0^{\circ}C$ to +70°C			±1405		
Input-referred offset voltage	$T_A = -40^{\circ}C$ to $+85^{\circ}C$			±1585	μV	В
	$T_A = -40^{\circ}C$ to $+125^{\circ}C$			±2000		
	$T_A = 0^{\circ}C$ to +70°C		±1.7	±9		
Input offset voltage drift ⁽²⁾	$T_A = -40^{\circ}C$ to $+85^{\circ}C$		±1.8	±9	-	В
	$T_A = -40^{\circ}C$ to $+125^{\circ}C$		±2	±10		
	$T_A = +25^{\circ}C$		160	210		Α
have the second second	$T_A = 0^{\circ}C$ to +70°C			221		
Input bias current	$T_A = -40^{\circ}C$ to $+85^{\circ}C$			222	nA	В
	$T_A = -40^{\circ}C$ to $+125^{\circ}C$			233		
	$T_A = 0^{\circ}C$ to +70°C			0.25		
Input bias current drift ⁽²⁾	$T_A = -40^{\circ}C$ to $+85^{\circ}C$			0.25	nA/°C	В
	$T_A = -40^{\circ}C$ to $+125^{\circ}C$			0.25		
	$T_A = +25^{\circ}C$		±5	±50		Α
	$T_A = 0^{\circ}C$ to +70°C			±59	-	
Input offset current	$T_A = -40^{\circ}C$ to $+85^{\circ}C$			±60	nA	В
	$T_A = -40^{\circ}C$ to $+125^{\circ}C$			±75		l
	$T_A = 0^{\circ}C$ to +70°C		±0.05	±0.2	-	В
Input offset current drift ⁽²⁾	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		±0.05	±0.2		
	$T_A = -40^{\circ}C$ to $+125^{\circ}C$		±0.05	±0.2	-	
INPUT		1			1	
	T _A = +25°C, CMRR > 87 dB		V _{S-} – 0.2	V _{S-}		Α
Common-mode input low	$T_A = -40^{\circ}$ C to +125°C, CMRR > 87 dB		V _{S-} – 0.2	V _{S-}	V	В
	$T_{A} = +25^{\circ}C, CMRR > 87 dB$	V _{S+} – 1.2	V _{S+} – 1.1			Α
Common-mode input high	$T_A = -40^{\circ}$ C to +125°C, CMRR > 87 dB	V _{S+} – 1.2	V _{S+} – 1.1		V	В
Common-mode rejection ratio		90	116		dB	Α
Input impedance common-mode			200 1.2			С
Input impedance differential mode			200 1		kΩ pF	С
OUTPUT	1				1	ļ
	T _A = +25°C		V _{S-} + 0.06	V _{S-} + 0.2		A
Single-ended output voltage: low	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$		V _{S-} + 0.06	V _{S-} + 0.2	V	В
Cingle and a subscription of the	$T_A = +25^{\circ}C$	V _{S+} - 0.2	V _{S+} – 0.11			А
Single-ended output voltage: high	$T_A = -40^{\circ}C$ to $+125^{\circ}C$	V _{S+} - 0.2	V _{S+} – 0.11		V	В
Output saturation voltage: high and low			110/60		mV	С
	$T_A = +25^{\circ}C$	±15	±22		~^^	А
Linear output current drive	$T_{A} = -40^{\circ}C \text{ to } +125^{\circ}C$	±15			mA	В

(2) Input offset voltage drift, input bias current drift, and input offset current drift are average values calculated by taking data at the end points, computing the difference, and dividing by the temperature range.



Electrical Characteristics: V_s = 2.7 V (continued)

Test conditions at $T_A = 25^{\circ}$ C, $V_{S+} = 2.7$ V, $V_{S-} = 0$ V, $V_{OCM} =$ open, $V_{OUT} = 2$ V_{PP} , $R_F = 2$ k Ω , $R_L = 2$ k Ω differential, G = 1 V/V, single-ended input, differential output, and input and output referenced to mid-supply, unless otherwise noted.

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS	TEST LEVEL ⁽¹⁾
POWER SUPPLY						
Specified operating voltage		2.5		5.5	V	В
Quiescent operating current/ch	$T_A = +25^{\circ}C, \overline{PD} = V_{S+}$		230	330		А
Quescent operating current/ch	$T_A = -40^{\circ}C$ to +125°C, $\overline{PD} = V_{S+}$		270	370	μA	В
Power-supply rejection (±PSRR)		87	108		dB	А
POWER DOWN						
Enable voltage threshold	Specified on above 2.1 V			2.1	V	А
Disable voltage threshold	Specified off below 0.7 V	0.7				А
Disable pin bias current	$\overline{PD} = V_{S-} + 0.5 V$		50	500	nA	А
Power-down quiescent current	$\overline{PD} = V_{S-} + 0.5 V$		0.5	2	μA	А
Turn-on time delay	Time from $\overline{\text{PD}}$ = high to V_{OUT} = 90% of final value, RL= 200 Ω		650			С
Turn-off time delay	Time from $\overline{\text{PD}}$ = low to V_{OUT} = 10% of original value, RL= 200 Ω		20		ns	
OUTPUT COMMON-MODE VOLT	AGE CONTROL (V _{OCM})					
Small-signal bandwidth	V_{OCM} input = 100 mV_{PP}		23		MHz	С
Slew rate	V_{OCM} input = 1 V_{STEP}		14		V/µs	С
Gain		0.99	0.996	1.01	V/V	А
Common-mode offset voltage	$\label{eq:offset} \begin{array}{l} \text{Offset} = \text{output common-mode voltage} - \text{V}_{\text{OCM}} \\ \text{input voltage} \end{array}$		±1	±5	mV	A
V _{OCM} input bias current	$V_{OCM} = (V_{S+} - V_{S-})/2$		±20	±100	nA	А
V _{OCM} input voltage range		0.8	0.75 to 1.9	1.75	V	А
V _{OCM} input impedance			100 1.6		$k\Omega \parallel pF$	С
Default voltage offset from $(V_{S+} - V_{S-})/2$	Offset = output common-mode voltage – $(V_{S+} - V_{S-})/2$		±3	±10	mV	А

5.4 Electrical Characteristics: V_s = 5 V

Test conditions at $T_A = +25^{\circ}C$, $V_{S+} = 5 V$, $V_{S-} = 0 V$, $V_{OCM} = open$, $V_{OUT} = 2 V_{PP}$, $R_F = 2 k\Omega$, $R_L = 2 k\Omega$ differential, G = 1 V/V, single-ended input, differential output, and input and output referenced to mid-supply, unless otherwise noted.

PARAMETER	CONDITIONS	MIN TYP	MAX	UNITS	TEST LEVEL ⁽¹⁾
AC PERFORMANCE	4				u
	V _{OUT} = 100 mV _{PP} , G = 1	36			
Small signal bandwidth	V _{OUT} = 100 mV _{PP} , G = 2	17			
Small-signal bandwidth	$V_{OUT} = 100 \text{ mV}_{PP}, \text{ G} = 5$	6		MHz	
	$V_{OUT} = 100 \text{ mV}_{PP}, \text{ G} = 10$	2.7			
Gain-bandwidth product	$V_{OUT} = 100 \text{ mV}_{PP}, \text{ G} = 10$	27		MHz	
Large-signal bandwidth	$V_{OUT} = 2 V_{PP}, G = 1$	36		MHz	
Bandwidth for 0.1 dB flatness	$V_{OUT} = 2 V_{PP}, G = 1$	15		MHz	
Slew rate, rise/fall, 25% to 75%		220/390		V/µs	
Rise/fall time, 10% to 90%		4.6/5.6		ns	
Settling time to 1%, rise and fall		25/20		ns	
Settling time to 0.1%, rise and fall	V _{OUT} = 2-V _{Step}	60/60		ns	
Settling time to 0.01%, rise and fall		150/110		ns	
Overshoot and undershoot, rise and fall		1/1	%		
	$f = 1 \text{ kHz}, \text{ V}_{OUT} = 1 \text{ V}_{RMS}$	-122			C
2nd-order harmonic distortion	f = 10 kHz	-128		dBc	
	f = 1 MHz	-60			
	$f = 1 \text{ kHz}, \text{ V}_{OUT} = 1 \text{ V}_{RMS}$	-130			
3rd-order harmonic distortion	f = 10 kHz	–137		dBc	
	f = 1 MHz	-71			
2nd-order intermodulation distortion	f = 1 MHz, 200 kHz tone spacing,	-85		dBc	
3rd-order intermodulation distortion	V_{OUT} envelope = 2 V_{PP}	-83			
Input voltage noise	f = 1 kHz	10		nV/√ Hz	
Voltage noise 1/f corner frequency		45		Hz	
Input current noise	f = 100 kHz	0.25		pA/√Hz	
Current noise 1/f corner frequency		6.5		kHz	
Overdrive recovery time	Overdrive = 0.5 V	65		ns	
Output balance error	V _{OUT} = 100 mV, f = 1 MHz	-67		dB	
Closed-loop output impedance	f = 1 MHz (differential)	2.5		Ω	

(1) Test levels (all values set by characterization and simulation): (A) 100% tested at +25°C; over temperature limits by characterization and simulation. (B) Not tested in production; limits set by characterization and simulation. (C) Typical value only for information.



Electrical Characteristics: V_s = 5 V (continued)

Test conditions at $T_A = +25^{\circ}C$, $V_{S+} = 5 \text{ V}$, $V_{S-} = 0 \text{ V}$, $V_{OCM} = \text{open}$, $V_{OUT} = 2 \text{ V}_{PP}$, $R_F = 2 \text{ k}\Omega$, $R_L = 2 \text{ k}\Omega$ differential, G = 1 V/V, single-ended input, differential output, and input and output referenced to mid-supply, unless otherwise noted.

PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNITS	TEST LEVEL ⁽¹⁾
DC PERFORMANCE						
Open-loop voltage gain (A _{OL})		100	114		dB	А
	$T_A = +25^{\circ}C$		±200	±1000		А
logut referred offect veltere	$T_A = 0^{\circ}C$ to +70°C			±1405		
Input-referred offset voltage	$T_A = -40^{\circ}C$ to $+85^{\circ}C$			±1650	μV	В
	$T_A = -40^{\circ}C$ to $+125^{\circ}C$			±2000		
	$T_A = 0^{\circ}C$ to +70°C		±1.7	±9		
Input offset voltage drift ⁽²⁾	$T_A = -40^{\circ}C$ to $+85^{\circ}C$		±2	±10	µV/°C	В
	$T_A = -40^{\circ}C$ to $+125^{\circ}C$		±2	±10		
	T _A = +25°C		160	210		А
	$T_A = 0^{\circ}C$ to +70°C			222		
Input bias current	$T_A = -40^{\circ}C$ to $+85^{\circ}C$			223	nA	В
	$T_A = -40^{\circ}C$ to $+125^{\circ}C$			235		
	$T_A = 0^{\circ}C$ to +70°C		0.04	0.25		В
Input bias current drift ⁽²⁾	$T_A = -40^{\circ}C$ to $+85^{\circ}C$		0.04	0.25	nA/°C	
	$T_A = -40^{\circ}C$ to $+125^{\circ}C$		0.04	0.25		
	T _A = +25°C		±5	±50	nA	А
	$T_A = 0^{\circ}C$ to +70°C			±59		В
Input offset current	$T_A = -40^{\circ}C$ to $+85^{\circ}C$			±60		
	$T_{A} = -40^{\circ}C \text{ to } +125^{\circ}C$			±75		
	$T_A = 0^{\circ}C$ to +70°C		±0.05	±0.2	nA/°C	В
Input offset current drift ⁽²⁾	$T_A = -40^{\circ}C$ to $+85^{\circ}C$		±0.05	±0.2		
	$T_A = -40^{\circ}C$ to $+125^{\circ}C$		±0.05	±0.2	-	
INPUT						1
	T _A = +25°C, CMRR > 87 dB		V _{S-} – 0.2	V _{S-}	V	А
Common-mode input: low	$T_A = -40^{\circ}$ C to +125°C, CMRR > 87 dB		V _S _ – 0.2	V _{S-}		В
2 1 1 1 1 1	T _A = +25°C, CMRR > 87 dB	V _{S+} – 1.2	V _{S+} –1.1	-	V	А
Common-mode input: high	$T_A = -40^{\circ}C$ to +125°C, CMRR > 87 dB	V _{S+} – 1.2				В
Common-mode rejection ratio		90	116		dB	А
Input impedance common-mode			200 1.2			С
Input impedance differential mode			200 1		- kΩ pF	С
OUTPUT	-	I			ł	4
Linear output voltage: low	T _A = +25°C		V _{S-} + 0.1	V _{S-} + 0.2	-	А
	$T_A = -40^{\circ}C$ to $+125^{\circ}C$			V _S _ + 0.2		В
Linear output voltage: high	$T_A = +25^{\circ}C$	V _{S+} – 0.25	V _{S+} - 0.12	-	V	A
	$T_A = -40^{\circ}C$ to $+125^{\circ}C$	V _{S+} – 0.25	V _{S+} – 0.12			В
Output saturation voltage: high/low			120/100		mV	С
	T _A = +25°C	±15	±25			А
Linear output current drive	$T_{A} = -40^{\circ}C \text{ to } +125^{\circ}C$	±15			mA	В

(2) Input offset voltage drift, input bias current drift, and input offset current drift are average values calculated by taking data at the end points, computing the difference, and dividing by the temperature range.

Electrical Characteristics: V_s = 5 V (continued)

Test conditions at $T_A = +25^{\circ}C$, $V_{S+} = 5 V$, $V_{S-} = 0 V$, $V_{OCM} = open$, $V_{OUT} = 2 V_{PP}$, $R_F = 2 k\Omega$, $R_L = 2 k\Omega$ differential, G = 1 V/V, single-ended input, differential output, and input and output referenced to mid-supply, unless otherwise noted.

PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNITS	TEST LEVEL ⁽¹⁾
POWER SUPPLY						
Specified operating voltage		2.5		5.5	V	В
Quisseent energing ourrent/ob	$T_A = 25^{\circ}C, \overline{PD} = V_{S+}$		250	350	μA	Α
Quiescent operating current/ch	$T_A = -40^{\circ}C$ to 125°C, $\overline{PD} = V_{S+}$		290	390		В
Power-supply rejection (±PSRR)		87	108		dB	Α
POWER DOWN						
Enable voltage threshold	Specified on above 2.1 V			2.1 V		А
Disable voltage threshold	Specified off below 0.7 V	0.7			v	Α
Disable pin bias current	$\overline{PD} = V_{S-} + 0.5 V$		50	500	nA	Α
Power-down quiescent current	$\overline{PD} = V_{S-} + 0.5 V$		0.5	2	μA	Α
Turn-on time delay	Time from \overline{PD} = high to V _{OUT} = 90% of final value, R _L = 200 Ω		600			С
Turn-off time delay	Time from \overline{PD} = low to V _{OUT} = 10% of original value, R _L = 200 Ω		15		ns	
OUTPUT COMMON-MODE VOLT	AGE CONTROL (V _{OCM})					
Small-signal bandwidth	V _{OCM} input = 100 mV _{PP}		24		MHz	С
Slew rate	V _{OCM} input = 1 V _{STEP}		15		V/µs	С
Gain		0.99	0.996	1.01	V/V	А
Common-mode offset voltage	Offset = output common-mode voltage – V _{OCM} input voltage		±1	±5	mV	A
V _{OCM} input bias current	$V_{OCM} = (V_{S+} - V_{S-})/2$		±20	±120	nA	Α
V_{OCM} input voltage range		0.95	0.75 to 4.15	4.0	V	A
V _{OCM} input impedance		65 0.86		$k\Omega \parallel pF$	С	
Default voltage offset from $(V_{S+} - V_{S-})/2$	Offset = output common-mode voltage – $(V_{S+} - V_{S-})/2$		±3	±10	mV	A



6 Device Information

6.1 **PIN Configurations**

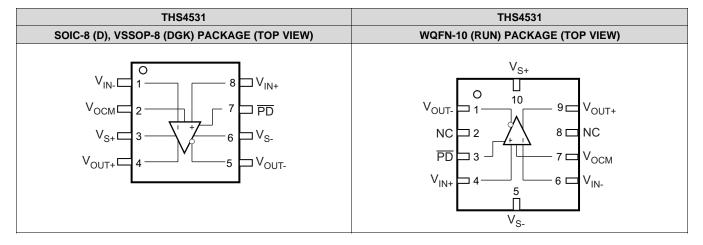


 Table 3. PIN Functions

NUMBER	NAME	DESCRIPTION				
THS4531 D, D	THS4531 D, DGK PACKAGE					
1	V _{IN-}	Inverted (negative) output feedback				
2	V _{OCM}	Common-mode voltage input				
3	V _{S+}	Amplifier positive power-supply input				
4	V _{OUT+}	Non-inverted amplifier output				
5	V _{OUT-}	Inverted amplifier output				
6	V _{S-}	Amplifier negative power-supply input. Note: V _S tied together on multichannel devices.				
7	PD	Power-down, \overline{PD} = logic low = low power mode, \overline{PD} = logic high = normal operation (pin must be driven)				
8	V _{IN+}	Non-inverted amplifier input				
THS4531 RUN	THS4531 RUN PACKAGE					
1	V _{OUT-}	Inverted amplifier output				
2, 8	NC	No internal connection				
3	PD	Power-down, PD = logic low = low power mode, PD = logic high = normal operation (pin must be driven)				
4	V _{IN+}	Noninverted amplifier input				
5	V _{S-}	Amplifier negative power-supply input. Note: V _S tied together on multichannel devices.				
6	V _{IN-}	Inverting amplifier input				
7	V _{OCM}	Common-mode voltage input				
9	V _{OUT+}	Noninverted amplifier output				
10	V _{S+}	Amplifier positive power-supply input				

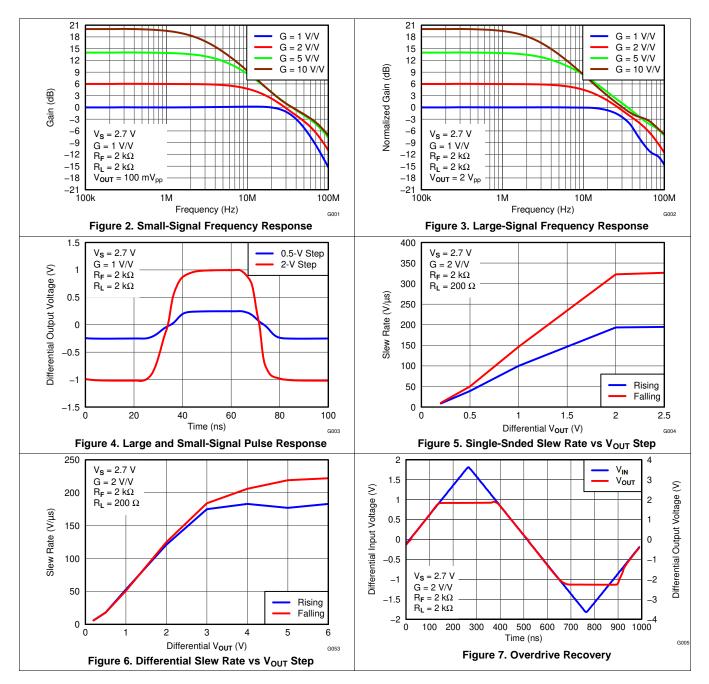


6.2 Table of Graphs

Description	V _S = 2.7 V	V _S = 5 V
Small-signal frequency response	Figure 2	Figure 35
Large-signal frequency response	Figure 3	Figure 36
Large- and small-signal pulse response	Figure 4	Figure 37
Single-ended slew rate versus V _{OUT} step	Figure 5	Figure 38
Differential slew rate versus V _{OUT} step	Figure 6	Figure 39
Overdrive recovery	Figure 7	Figure 40
10-kHz FFT on audio analyzer	Figure 8	Figure 41
Harmonic distortion versus frequency	Figure 9	Figure 42
Harmonic distortion versus output voltage at 1 MHz	Figure 10	Figure 43
Harmonic distortion versus gain at 1 MHz	Figure 11	Figure 44
Harmonic distortion versus load at 1 MHz	Figure 12	Figure 45
Harmonic distortion versus V _{OCM} at 1 MHz	Figure 13	Figure 46
Two-tone, 2nd and 3rd order intermodulation distortion versus frequency	Figure 14	Figure 47
Single-ended output voltage swing versus load resistance	Figure 15	Figure 48
Single-ended output saturation voltage versus load current	Figure 16	Figure 49
Main amplifier differential output impedance versus frequency	Figure 17	Figure 50
Frequency response versus C _{LOAD}	Figure 18	Figure 51
R _O versus C _{LOAD}	Figure 19	Figure 52
Rejection ratio versus frequency	Figure 20	Figure 53
Turn-on time	Figure 21	Figure 54
Turn-off time	Figure 22	Figure 55
Input-referred voltage noise and current noise spectral density	Figure 23	Figure 56
Main amplifier differential open-loop gain and phase versus frequency	Figure 24	Figure 57
Output balance error versus frequency	Figure 25	Figure 58
V _{OCM} small signal frequency response	Figure 26	Figure 59
V _{OCM} large and small signal pulse response	Figure 27	Figure 60
V _{OCM} input impedance versus frequency	Figure 28	Figure 61
Count versus input offset current	Figure 29	Figure 62
Count versus input offset current temperature drift	Figure 30	Figure 63
Input offset current versus temperature	Figure 31	Figure 64
Count versus input offset voltage	Figure 32	Figure 65
Count versus input offset voltage temperature drift	Figure 33	Figure 66
Input offset voltage versus temperature	Figure 34	Figure 67



7 Typical Characteristics: $V_s = 2.7 V$

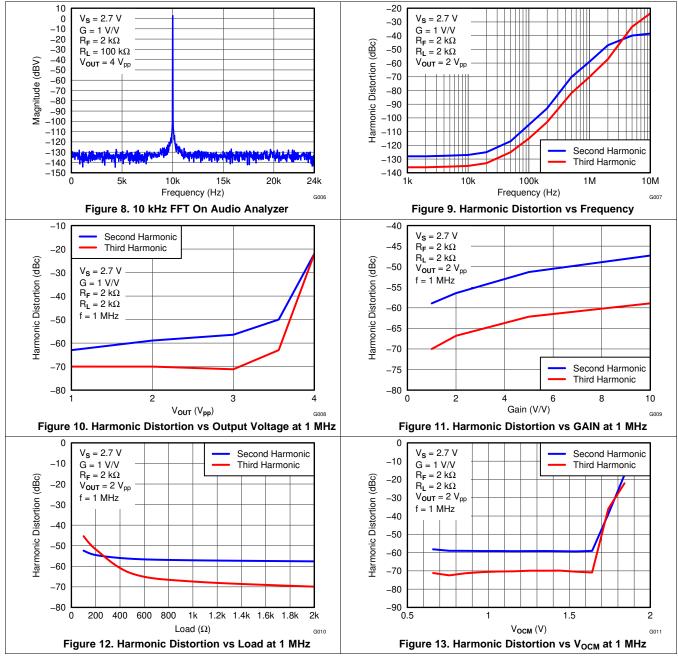


THS4531 SLOS358C – SEPTEMBER 2011 – REVISED APRIL 2020

TEXAS INSTRUMENTS

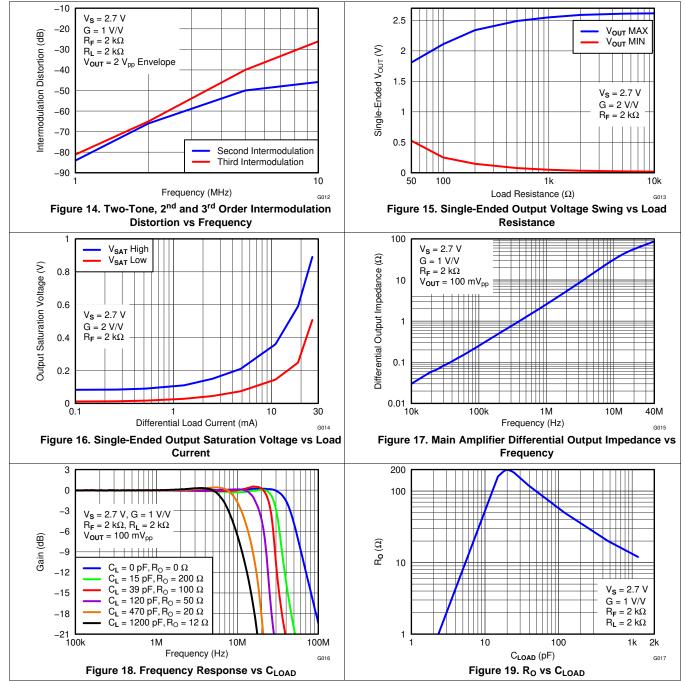
www.ti.com

Typical Characteristics: V_s = 2.7 V (continued)



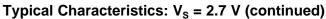


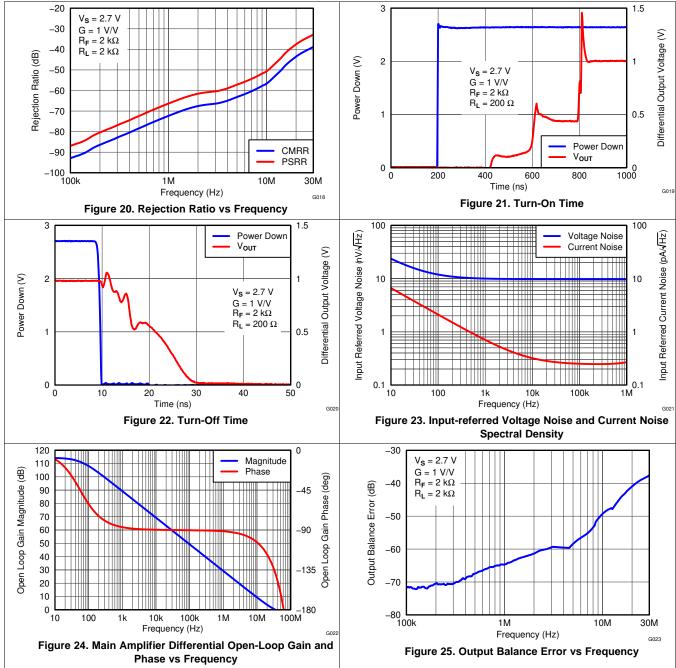
Typical Characteristics: V_s = 2.7 V (continued)



TEXAS INSTRUMENTS

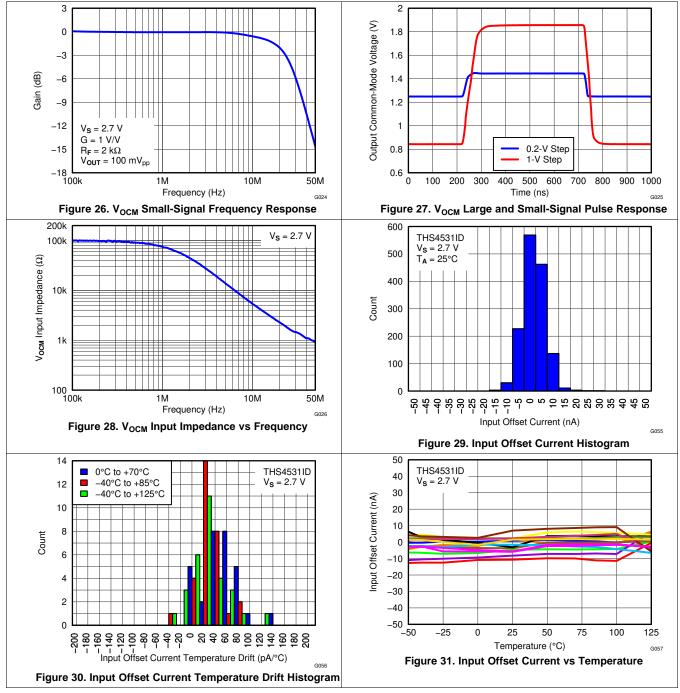
www.ti.com





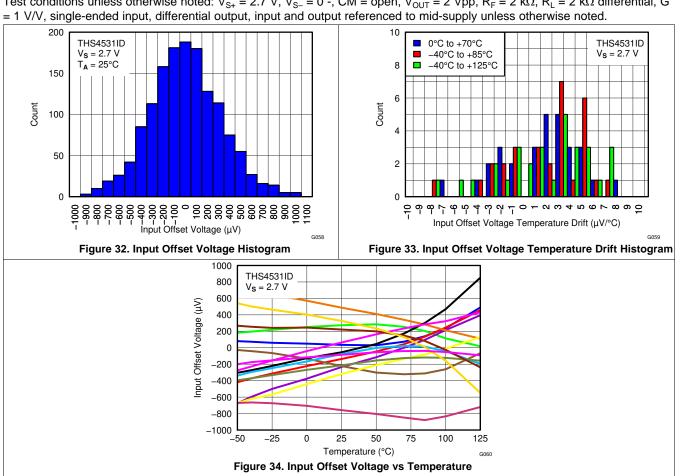


Typical Characteristics: V_s = 2.7 V (continued)



ÈXAS NSTRUMENTS

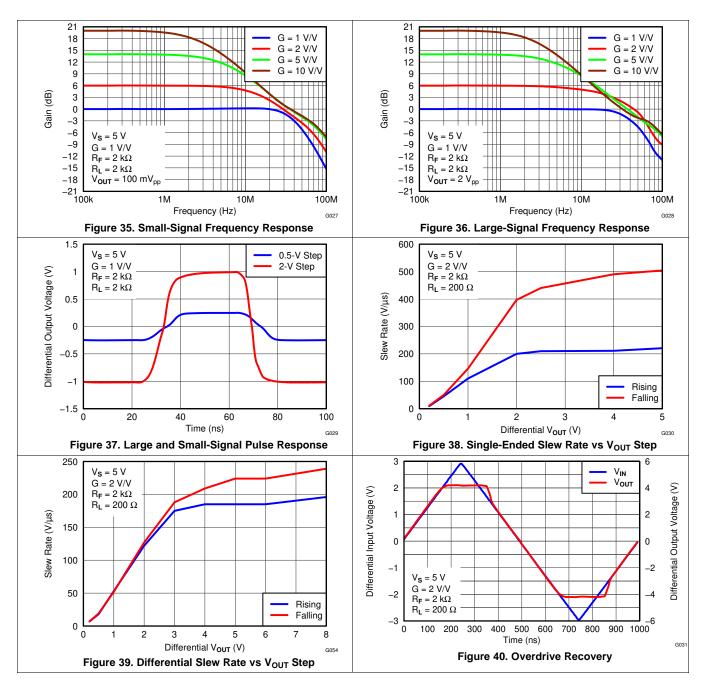
www.ti.com



Typical Characteristics: V_s = 2.7 V (continued)



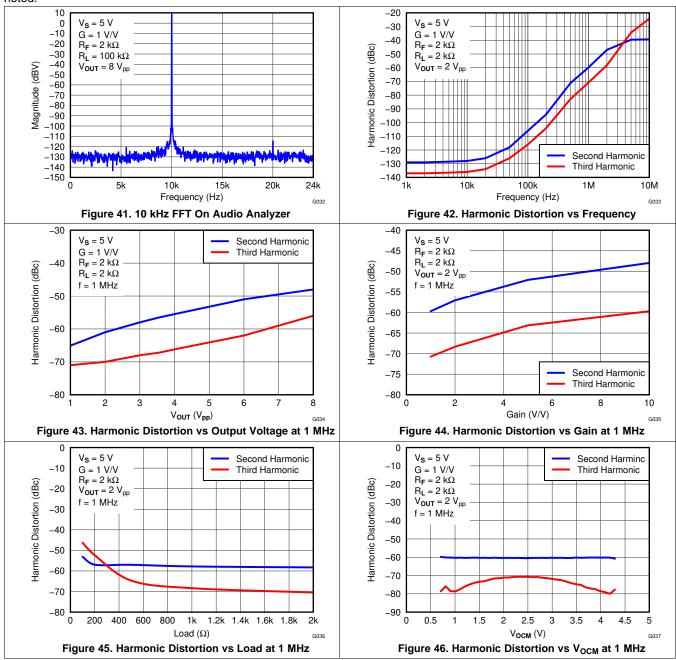
8 Typical Characteristics: V_s = 5 V



TEXAS INSTRUMENTS

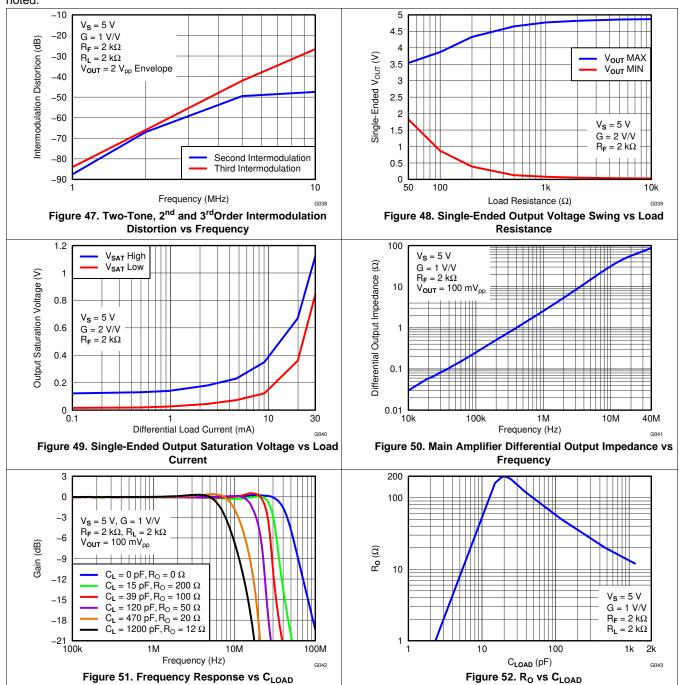
www.ti.com

Typical Characteristics: V_s = 5 V (continued)



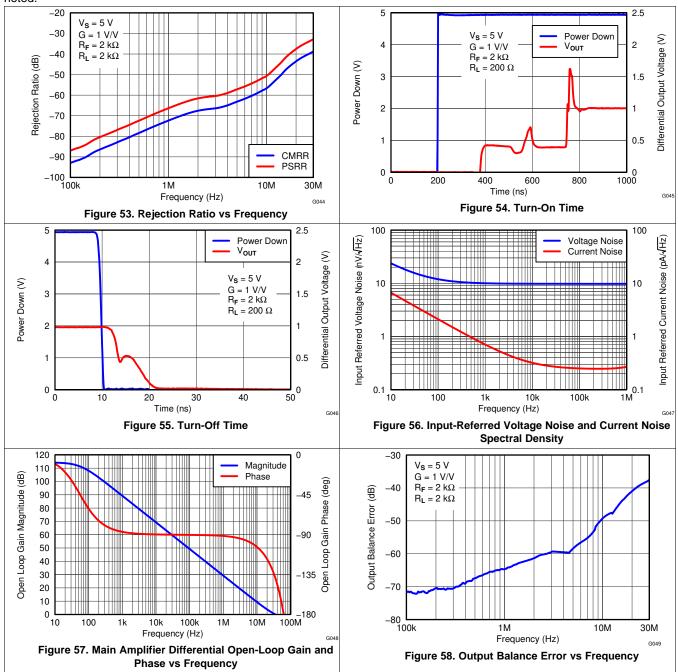


Typical Characteristics: V_s = 5 V (continued)



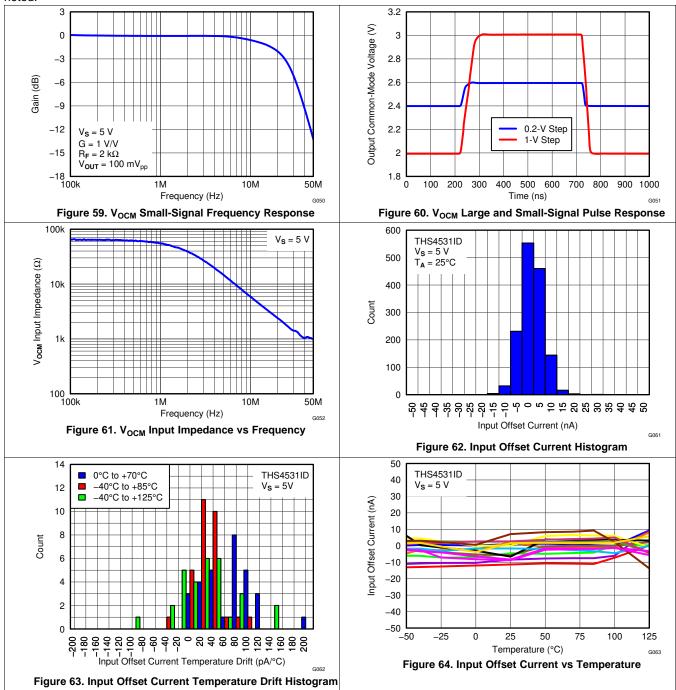


Typical Characteristics: V_s = 5 V (continued)





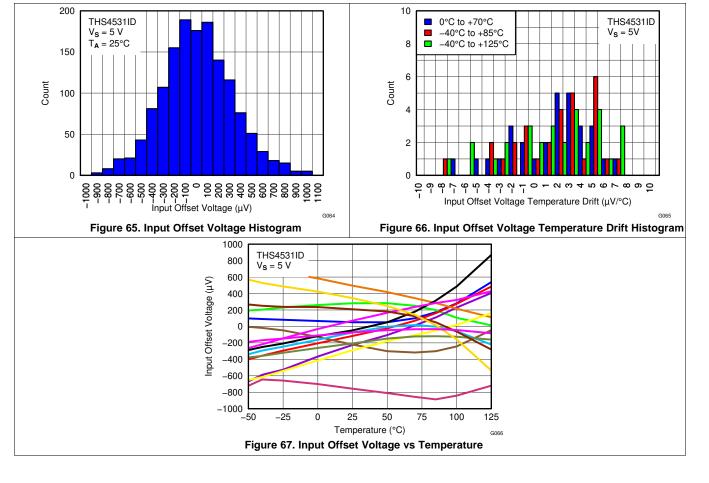
Typical Characteristics: V_s = 5 V (continued)



Typical Characteristics: V_s = 5 V (continued)

Test conditions unless otherwise noted: $V_{S+} = 5 V$, $V_{S-} = 0 V$, $V_{OCM} = open$, $V_{OUT} = 2 Vpp$, $R_F = 2 k\Omega$, $R_L = 2 k\Omega$ Differential, G = 1 V/V, Single-Ended Input, Differential Output, Input and Output Referenced to mid-supply, $T_A = 25^{\circ}C$ unless otherwise noted.





www.ti.com



9 Application Information

9.1 Typical Characteristics Test Circuits

Figure 68 shows the general test circuit built on the EVM that was used for testing the THS4531. For simplicity, power supply decoupling is not shown – please see layout in the applications section for recommendations. Depending on the test conditions, component values are changed per Table 4 and Table 5, or as otherwise noted. Some of the signal generators used are ac coupled 50 Ω sources and a 0.22 µF cap and 49.9 Ω resistor to ground are inserted across R_{IT} on the un-driven or alternate input as shown to balance the circuit. Split-power supply is used to ease the interface to common lab test equipment, but if properly biased, the amplifier can be operated single-supply as described in the applications section with no impact on performance. For most of the tests, the devices are tested with single ended input and a transformer on the output to convert the differential output to single ended because common lab test equipment have single ended inputs and outputs. Performance is the same or better with differential input and differential output.

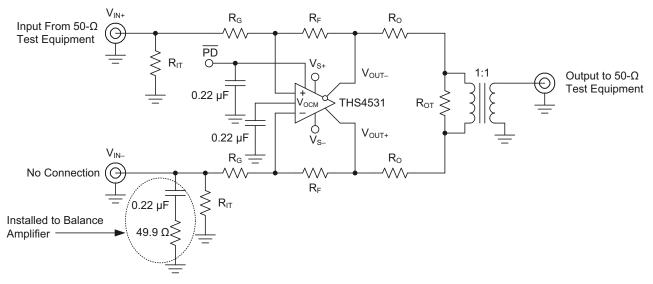


Figure 68. General Test Circuit

GAIN	R _F	R _G	R _{IT}
1 V/V	2 kΩ	2 kΩ	51.1 Ω
2 V/V	2 kΩ	1 kΩ	52.3 Ω
5 V/V	2 kΩ	392 Ω	53.6 Ω
10 V/V	2 kΩ	187 kΩ	57.6 Ω

Table 4. Gain Con	ponent Values for	[•] Single-Ended Input ⁽¹⁾
-------------------	-------------------	--

(1) Note components are chosen to achieve gain and 50-Ω input termination. Resistor values shown are closest standard values so gains are approximate.

Table 5. Load Component Values For 1:1 Differential to Single-Ended Output Transformer⁽¹⁾

RL	R _o	R _{ot}	ATTEN
100 Ω	25 Ω	open	6
200 Ω	86.6 Ω	69.8 Ω	16.8
499 Ω	237 Ω	56.2 Ω	25.5
1 kΩ	487 Ω	52.3 Ω	31.8
2 kΩ	976 Ω	51.1 Ω	37.9

(1) Note the total load includes $50-\Omega$ termination by the test equipment. Components are chosen to achieve load and $50-\Omega$ line termination through a 1:1 transformer. Resistor values shown are closest standard values so loads are approximate.



Due to the voltage divider on the output formed by the load component values, the amplifier's output is attenuated. The column *Atten* in Table 5 shows the attenuation expected from the resistor divider. When using a transformer at the output as shown in Figure 68, the signal will see slightly more loss due to transformer and line loss, and these numbers will be approximate. The standard output load used for most tests is 2 k Ω with associated 37.9 dB of loss.

9.1.1 Frequency Response and Output Impedance

The circuit shown in Figure 68 is used to measure the frequency response of the amplifier.

A network analyzer is used as the signal source and the measurement device. The output impedance of the network analyzer is 50- Ω and is DC coupled. R_{IT} and R_G are chosen to impedance match to 50 Ω and maintain the proper gain. To balance the amplifier, a 49.9 Ω resistor to ground is inserted across R_{IT} on the alternate input.

The output is routed to the input of the network analyzer via 50 Ω coax. For 2 k load, 37.9 dB is added to the measurement to refer back to the amplifier's output per Table 5.

For output impedance, the signal is injected at V_{OUT} with V_{IN} left open. The voltage drop across the 2x R_O resistors is measured with a high impedance differential probe and used to calculate the impedance seen looking into the amplifier's output.

9.1.2 Distortion

At 1 MHz and above, the circuit shown in Figure 68 is used to measure harmonic, intermodulation distortion, and output impedance of the amplifier.

A signal generator is used as the signal source and the output is measured with a spectrum analyzer. The output impedance of the signal generator is 50 Ω and is AC coupled. R_{IT} and R_G are chosen to impedance match to 50 Ω and maintain the proper gain. To balance the amplifier, a 0.22 μ F cap and 49.9 Ω resistor to ground is inserted across R_{IT} on the alternate input. A low-pass filter is inserted in series with the input to reduce harmonics generated at the signal source. The level of the fundamental is measured and then a high-pass filter is inserted at the output to reduce the fundamental so it does not generate distortion in the input of the spectrum analyzer.

Distortion in the audio band is measured using an audio analyzer. Refer to audio measurement section for detail.

9.1.3 Slew Rate, Transient Response, Settling Time, Overdrive, Output Voltage, and Turn-On and Turn-Off Time

The circuit shown in Figure 69 is used to measure slew rate, transient response, settling time, overdrive recovery, and output voltage swing. Turn-on and turn-off times are measured with 50 Ω input termination on the PD input, by replacing the 0.22 µF capacitor with 49.9 Ω resistor.



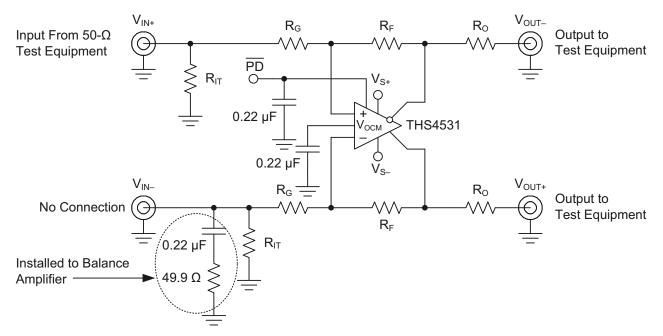


Figure 69. Slew Rate, Transient Response, Settling Time, Z_o, Overdrive Recovery, V_{OUT} Swing, and Turn-On and Trun-Off Test Circuit

9.1.4 Common-Mode and Power Supply Rejection

The circuit shown in Figure 70 is used to measure the CMRR. The signal from the network analyzer is applied common-mode to the input.

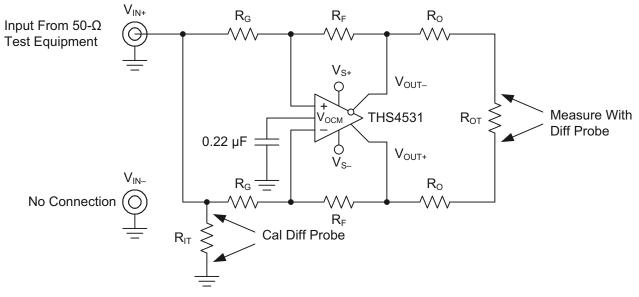




Figure 71 is used to measure the PSRR of V_{S+} and V_{S-} . The power supply is applied to the network analyzer's DC offset input. For both CMRR and PSRR, the output is probed using a high impedance differential probe across R_{OT} .

Copyright © 2011–2020, Texas Instruments Incorporated

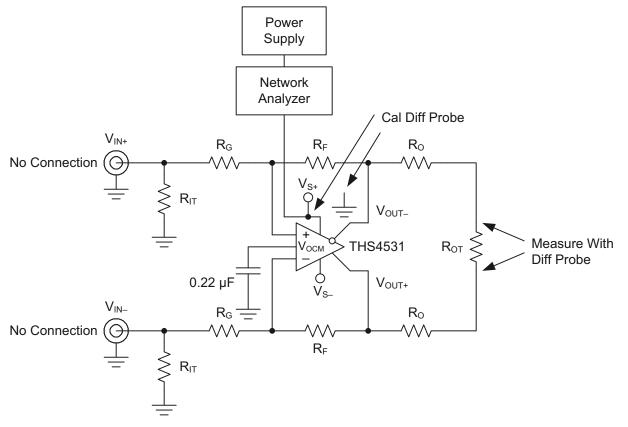
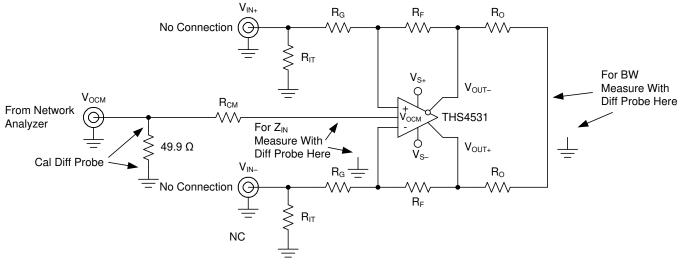


Figure 71. PSRR Test Circuit

9.1.5 V_{OCM} Input

The circuit shown in Figure 72 is used to measure the transient response, frequency response and input impedance of the V_{OCM} input. For these tests, the cal point is across the 49.9 Ω V_{OCM} termination resistor. Transient response and frequency response are measured with R_{CM} = 0 Ω and using a high impedance differential probe at the summing junction of the two R_O resistors, with respect to ground. The input impedance is measured using a high impedance differential probe at the V_{OCM} input. For the amplifier's V_{OCM} pin and the drop across R_{CM} is used to calculate the impedance seen looking into the amplifier's V_{OCM} input.





www.ti.com



9.1.6 Balance Error

The circuit shown in Figure 73 is used to measure the balance error of the main differential amplifier. A network analyzer is used as the signal source and the measurement device. The output impedance of the network analyzer is 50 Ω and is DC coupled. R_{IT} and R_G are chosen to impedance match to 50 Ω and maintain the proper gain. To balance the amplifier, a 49.9 Ω resistor to ground is inserted across R_{IT} on the alternate input. The output is measured using a high impedance differential probe at the summing junction of the two R_O resistors, with respect to ground.

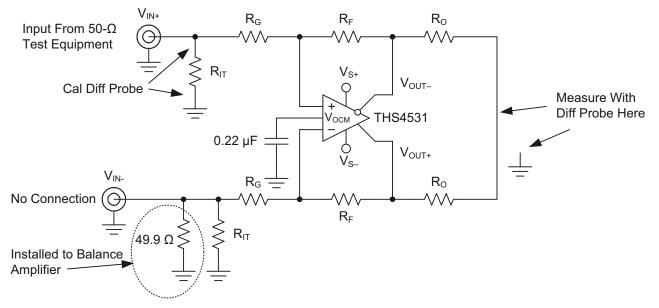


Figure 73. Balance Error Test Circuit

9.2 Application Circuits

The following circuits show application information for the THS4531. For simplicity, power supply decoupling capacitors are not shown in these diagrams – please see the EVM and Layout Recommendations section for recommendations. For more detail on the use and operation of fully differential op amps refer to application report *Fully-Differential Amplifiers* SLOA054D.

9.2.1 Differential Input to Differential Output Amplifier

The THS4531 is a fully differential op amp and can be used to amplify differential <u>inp</u>ut signals to differential output signals. A basic block diagram of the circuit is shown in Figure 74 (V_{OCM} and PD inputs not shown). The gain of the circuit is set by R_F divided by R_G .

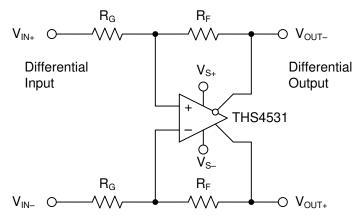


Figure 74. Differential Input to Differential Output Amplifier

9.2.2 Single-Ended Input to Differential Output Amplifier

The THS4531 can also be used to amplify and convert single-ended input signals to differential output signals. A basic block diagram of the circuit is shown in Figure 75 (V_{OCM} and \overline{PD} inputs not shown). The gain of the circuit is again set by R_F divided by R_G .

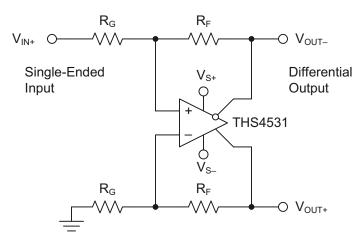


Figure 75. Single-Ended Input to Differential Output Amplifier

9.2.3 Differential Input to Single-Ended Output Amplifier

Fully differential op amps like the THS4531 are not recommended for differential to single-ended conversion. This application is best performed with an instrumentation amplifier or with a standard op amp configured as a classic differential amplifier. See application section of the OPA835 data sheet (SLOS713).



Application Circuits (continued)

9.2.4 Input Common-Mode Voltage Range

The input common-model voltage of a fully differential op amp is the voltage at the + and - input pins of the op amp.

It is important to not violate the input common-mode voltage range (V_{ICR}) of the op amp. Assuming the op amp is in linear operation the voltage across the input pins is only a few millivolts at most. So finding the voltage at one input pin will determine the input common-mode voltage of the op amp.

Treating the negative input as a summing node, the voltage is given by:

$$\left(V_{OUT+} \times \frac{R_{G}}{R_{G} + R_{F}}\right) + \left(V_{IN-} \times \frac{R_{F}}{R_{G} + R_{F}}\right)$$
(1)

To determine the V_{ICR} of the op amp, the voltage at the negative input is evaluated at the extremes of V_{OUT+} .

As the gain of the op amp increases, the input common-mode voltage becomes closer and closer to the input common-mode voltage of the source.

9.2.5 Setting the Output Common-Mode Voltage

The output common-model voltage is set by the voltage at the V_{OCM} pin and the internal circuit works to maintain the output common-mode voltage as close as possible to this voltage. If left unconnected, the output commonmode is set to mid-supply by internal circuitry, which may be over-driven from an external source. Figure 76 is representative of the V_{OCM} input. The internal V_{OCM} circuit has about 24 MHz of -3 dB bandwidth, which is required for best performance, but it is intended to be a DC bias input pin. Bypass capacitors are recommended on this pin to reduce noise. The external current required to overdrive the internal resistor divider is given approximately by the formula:

$$I_{EXT} = \frac{2V_{OCM} - (V_{S+} - V_{S-})}{1.25 \text{ M}\Omega}$$
(2)

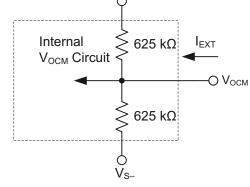
where V_{OCM} is the voltage applied to the V_{OCM} pin.



9.2.6 Single-Supply Operation

To facilitate testing with common lab equipment, the THS4531 EVM is built to allow for split-supply operation and most of the data presented in this data sheet was taken with split-supply power inputs. But the device is designed for use with single-supply power operation and can easily be used with single-supply power without degrading the performance. The only requirement is to bias the device properly and the specifications in this data sheet are given for single supply operation.

Copyright © 2011-2020, Texas Instruments Incorporated



V_{S+}

THS4531

Texas Instruments

www.ti.com

Application Circuits (continued)

9.2.7 Low Power Applications and the Effects of Resistor Values on Bandwidth

The THS4531 is designed for the nominal value of R_F to be 2 k Ω . This gives excellent distortion performance, maximum bandwidth, best flatness, and best pulse response. It also loads the amplifier. For example, in gain of 1 with $R_F = R_G = 2 k\Omega$, R_G to ground, and $V_{OUT+} = 4 V$, 1 mA of current will flow through the feedback path to ground. In low power applications, it is desirable to reduce this current by increasing the gain setting resistors values. Using larger value gain resistors has two primary side effects (other than lower power) due to their interaction with the device and PCB parasitic capacitance:

- 1. Lowers the bandwidth.
- 2. Lowers the phase margin
 - a. This will cause peaking in the frequency response.
 - b. And will cause over shoot and ringing in the pulse response.

Figure 77 shows the small signal frequency response for gain of 1 with R_F and R_G equal to 2 k Ω , 10 k Ω , and 100 k Ω . The test was done with $R_L = 2 k\Omega$. Due to loading effects of R_L , lower values may reduce the peaking, but higher values will not have a significant effect.

As expected, larger value gain resistors cause lower bandwidth and peaking in the response (peaking in frequency response is synonymous with overshoot and ringing in pulse response).

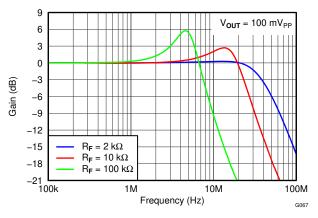


Figure 77. THS4531 Frequency Response with Various Gain Setting Resistor Values

9.2.8 Driving Capacitive Loads

The THS4531 is designed for a nominal capacitive load of 2 pF (differentially). When driving capacitive loads greater than this, it is recommended to use small resisters (R_0) in series with the output as close to the device as possible. Without R_0 , capacitance on the output will interact with the output impedance of the amplifier causing phase shift in the loop gain of the amplifier that will reduce the phase margin resulting in:

- 1. Peaking in the frequency response.
- 2. Overshoot, undershoot, and ringing in the time domain response with a pulse or square-wave signal.
- 3. May lead to instability or oscillation.

Inserting R_O will compensate the phase shift and restore the phase margin, but it will also limit bandwidth. The circuit shown in Figure 69 is used to test for best R_O versus capacitive loads, C_L, with a capacitance placed differential across the V_{OUT+} and V_{OUT-} along with 2 k Ω load resistor, and the output is measure with a differential probe. Figure 78 shows the optimum values of R_O versus capacitive loads, C_L, and Figure 79 shows the frequency response with various values. Performance is the same on both 2.7 V and 5 V supply.



Application Circuits (continued)

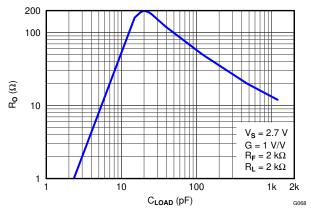


Figure 78. Recommended Series Output Resistor vs Capacitive Load for Flat Frequency Response

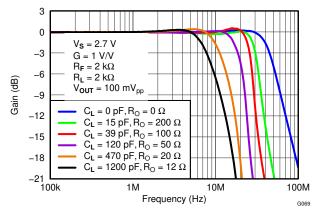
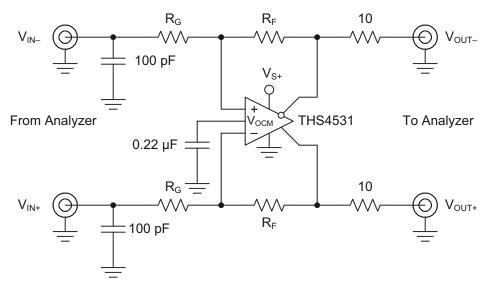


Figure 79. Frequency Response for Various R₀ and C_L Values

9.2.9 Audio Performance

The THS4531 provides excellent audio performance with very low quiescent power. To show performance in the audio band, the device was tested with an audio analyzer. THD+N and FFT tests were run at 1 Vrms output voltage. Performance is the same on both 2.7 V and 5 V supply. Figure 80 is the test circuit used, and Figure 81 and Figure 82 show performance of the analyzer. In the FFT plot the harmonic spurs are at the testing limit of the analyzer, which means the THS4531 is actually much better than can be directly measured. Because the THS4531 distortion performance cannot be directly measured in the audio band it is estimated from measurement in high noise gain configuration correlated with simulation.

Application Circuits (continued)





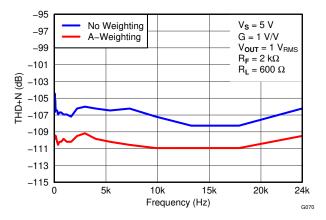


Figure 81. THD+N on Audio Analyzer, 10 Hz to 24 kHz

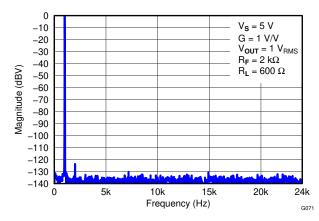


Figure 82. 1 kHz FFT Plot on Audio Analyzer



Application Circuits (continued)

9.2.10 Audio On and Off Pop Performance

The THS4531 is tested to show on and off pop performance by connecting a speaker between the differential outputs and switching on and off the power supply, and also by using the power down function of the THS4531. Testing was done with and without tones. During these tests no audible pop could be heard.

With no input tone, Figure 83 shows the voltage waveforms when switching power on to the THS4531 and Figure 84 shows voltage waveforms when turning power off. The transients during power on and off show no audible pop should be heard.

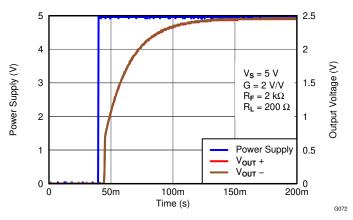


Figure 83. Power Supply Turn On Pop Performance

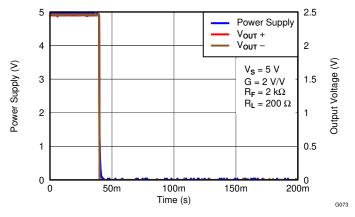


Figure 84. Power Supply Turn Off Pop Performance

With no input tone, Figure 85 shows the voltage waveforms using the \overline{PD} pin to enable and disable the THS4531. The transients during power on and off show no audible pop should be heard.

Application Circuits (continued)

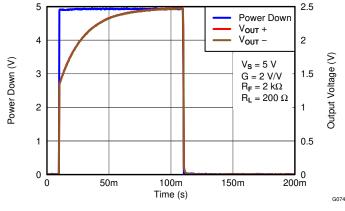


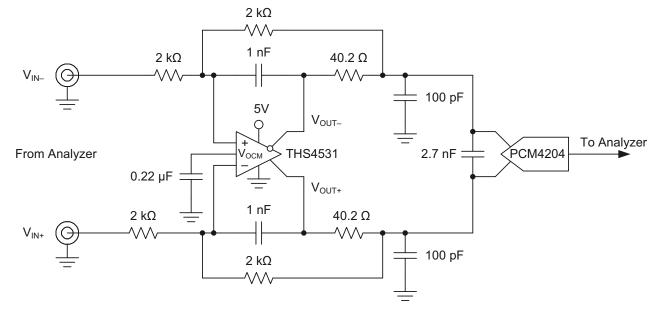
Figure 85. PD Enable Pop Performance

9.3 Audio ADC Driver Performance: THS4531 AND PCM4204 Combined Performance

To show achievable performance with a high performance audio ADC, the THS4531 is tested as the drive amplifier for the PCM4204. The PCM4204 is a high-performance, four-channel analog-to-digital (A/D) converter designed for professional and broadcast audio applications. The PCM4204 architecture utilizes a 1-bit delta-sigma modulator per channel incorporating an advanced dither scheme for improved dynamic performance, and supports PCM output data. The PCM4204 provides flexible serial port interface and many other advanced features. Please refer to its data sheet for more information.

The PCM4204 EVM is used to test the audio performance of the THS4531 as a drive amplifier. The standard PCM4204 EVM is provided with 4x OPA1632 fully differential amplifiers, which use the same pin out as the THS4531. For testing, one of these amplifiers is replaced with a THS4531 device in same package (MSOP), gain changed to 1 V/V, and power supply changed to single supply +5 V. Figure 86 shows the circuit. With single supply +5 V supply the output common-mode of the THS4531 defaults to +2.5 V as required at the input of the PCM4204. So the resistor connecting the V_{OCM} input of the THS4531 to the input common-mode drive from the PCM4204 is optional and no performance change was noted with it connected or removed. The EVM power connections were modified by connecting positive supply inputs, +15 V, +5 VA and +5 VD, to a +5 V external power supply (EXT +3.3 was not used) and connecting -15 V and all ground inputs to ground on the external power supply so only one external +5 V supply was needed to power all devices on the EVM.





Audio ADC Driver Performance: THS4531 AND PCM4204 Combined Performance (continued)



An audio analyzer is used to provide an analog audio input to the EVM and the PCM formatted digital output is read by the digital input on the analyzer. Data was taken at $f_S = 96$ kHz, and audio output uses PCM format. Other data rates and formats are expected to show similar performance in line with that shown in the data sheet.

Figure 87 shows the THD+N vs Frequency with no weighting and Figure 88 shows an FFT with 1 kHz input tone. Input signal to the PCM4204 for these tests is -0.5 dBFS. Table 6 summarizes results of testing using the THS4531 + PCM4204 versus typical Data Sheet performance, and show it make an excellent drive amplifier for this ADC.

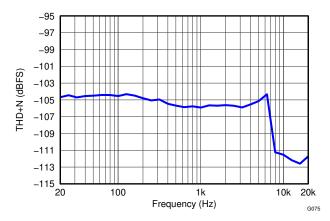


Figure 87. THS4531 + PCM4204 THD+N vs Frequency with No Weighting

NSTRUMENTS

FXAS

Audio ADC Driver Performance: THS4531 AND PCM4204 Combined Performance (continued)

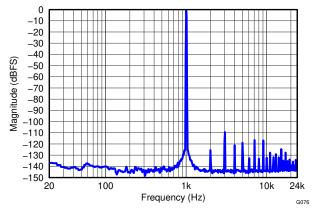


Figure 88. THS4531 + PCM4204 1 kHz FFT

Table 6. 1 kHz AC Analysis: Test Circuit versus PCM4204 Data Sheet Typical Specifications (f_S = 96 kSPS)

CONFIGURATION	TONE	THD + N
THS4531 + PCM4204	1 kHz	-106 dB
PCM4204 data sheet (typical)	1 kHz	-103 dB

9.4 SAR ADC Performance

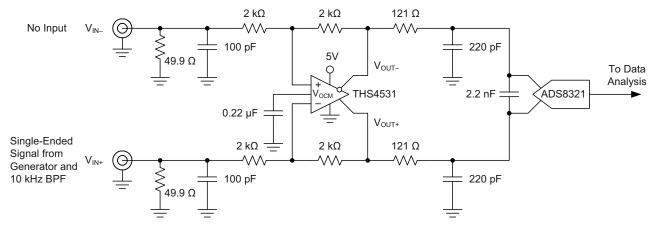
9.4.1 THS4531 and ADS8321 Combined Performance

To show achievable performance with a high performance SAR ADC, the THS4531 is tested as the drive amplifier for the ADS8321. The ADS8321 is a 16-bit, SAR ADC that offers excellent AC and DC performance, with ultra-low power and small size. The circuit shown in Figure 89 is used to test the performance. Data was taken using the ADS8321 at 100 kSPS with input frequency of 10 kHz and signal levels 0.5 dB below full scale. The FFT plot of the spectral performance is in Figure 90. A summary of the FFT analysis results are in Table 7 along with ADS8321 typical data sheet performance at $f_S = 100$ kSPS. Please refer to its data sheet for more information.

The standard ADS8321 EVM and THS4531 EVM are modified to implement the schematic in Figure 89 and used to test the performance of the THS4531 as a drive amplifier. With single supply +5 V supply the output common-mode of the THS4531 defaults to +2.5 V as required at the input of the ADS8321 so the V_{OCM} input of the THS4531 simply bypassed to GND with 0.22 μ F capacitor. The summary of results of the FFT analysis versus typical data sheet performance shown in Table 7 show the THS4531 will make an excellent drive amplifier for this ADC.



SAR ADC Performance (continued)





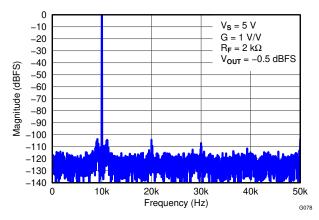


Figure 90. THS4531 + ADS8321 1-kHz FFT

CONFIGURATION	TONE	SIGNAL	SNR	THD	SINAD	SFDR
THS4531 + ADS8321	10 kHz	-0.5 dBFS	87 dBc	-96 dBc	87 dBc	100 dBc
ADS8321 data sheet (typical)	10 kHz	-0.5 dBFS	87 dBc	-86 dBc	84 dBc	86 dBc

Table 7. 10 kHz FFT Analysis Summary

9.4.2 THS4531 and ADS7945 Combined Performance

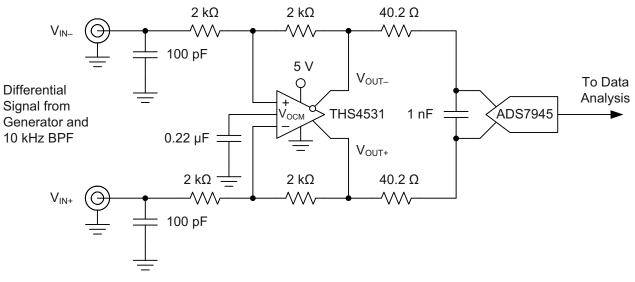
To show achievable performance with a high performance SAR ADC, the THS4531 is tested as the drive amplifier for the ADS7945. The ADS7945 is a 14-bit, SAR ADC that offers excellent AC and DC performance, with low power and small size. The circuit shown in Figure 91 is used to test the performance. Data was taken using the ADS7945 at 2MSPS with input frequency of 10 kHz and signal level 0.5 dB below full scale. The FFT plot of the spectral performance is in Figure 92. A summary of the FFT analysis results are in Table 8 along with ADS7945 typical data sheet performance at $f_s = 2$ MSPS. Please refer to its data sheet for more information.

The standard ADS7945 EVM and THS4531 EVM are modified to implement the schematic in Figure 91 and used to test the performance of the THS4531 as a drive amplifier. With single supply +5 V supply the output common-mode of the THS4531 defaults to +2.5 V as required at the input of the ADS7945 so the V_{OCM} input of the THS4531 simply bypassed to GND with 0.22 μ F capacitor. The summary of results of the FFT analysis versus typical data sheet performance shown in Table 8 show the THS4531 will make an excellent drive amplifier for this ADC.

Copyright © 2011–2020, Texas Instruments Incorporated

TEXAS INSTRUMENTS

www.ti.com





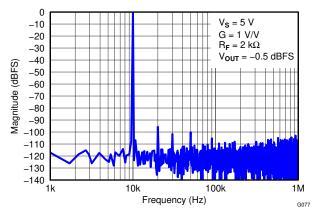


Figure 92. THS4531 and ADS7945 Test Circuit

Table 8.	10 kHz	FFT	Analysis	Summary
			Analysis	Cammary

CONFIGURATION	TONE	SIGNAL	SNR	THD	SFDR
THS4531 + ADS7945	10 kHz	-0.5 dBFS	83 dBc	-93 dBc	96 dBc
ADS7945 Data sheet (typical)	10 kHz	-0.5 dBFS	84 dBc	-92 dBc	94 dBc



9.5 EVM and Layout Recommendations

The THS4531 EVM (SLOU334) should be used as a reference when designing the circuit board. It is recommended to follow the EVM layout of the external components near to the amplifier, ground plane construction, and power routing as closely as possible. General guidelines are:

- 1. Signal routing should be direct and as short as possible into and out of the op amp.
- 2. The feedback path should be short and direct avoiding vias if possible.
- 3. Ground or power planes should be removed from directly under the amplifier's input and output pins.
- 4. A series output resistor is recommended to be placed as near to the output pin as possible. See Figure 78 *Recommended Series Output Resistor vs. Capacitive Load* for recommended values given expected capacitive load of design.
- 5. A 2.2 μF power supply decoupling capacitor should be placed within 2 inches of the device and can be shared with other op amps. For split supply, a capacitor is required for both supplies.
- 6. A 0.1 μF power supply decoupling capacitor should be placed as near to the power supply pins as possible. Preferably within 0.1 inch. For split supply, a capacitor is required for both supplies.
- 7. The PD pin uses TTL logic levels referenced to the negative supply voltage (V_{S-}). When not used it should tied to the positive supply to enable the amplifier. When used, it must be actively driven high or low and should not be left in an indeterminate logic state. A bypass capacitor is not required, but can be used for robustness in noisy environments.

TEXAS INSTRUMENTS

www.ti.com

10 Device and Documentation Support

10.1 Device Support

10.1.1 Third-Party Products Disclaimer

TI'S PUBLICATION OF INFORMATION REGARDING THIRD-PARTY PRODUCTS OR SERVICES DOES NOT CONSTITUTE AN ENDORSEMENT REGARDING THE SUITABILITY OF SUCH PRODUCTS OR SERVICES OR A WARRANTY, REPRESENTATION OR ENDORSEMENT OF SUCH PRODUCTS OR SERVICES, EITHER ALONE OR IN COMBINATION WITH ANY TI PRODUCT OR SERVICE.

10.2 Documentation Support

For related documentation see the following:

- ADS7945 and ADS7946 14-Bit, 2 MSPS, Dual-Channel, Differential/Single-Ended, Ultra low-Power Analogto-Digital Converters, SBAS539
- ADS8321 16-Bit, High Speed, Micro Power Sampling Analog-to-Digital converter, SBAS123
- Extending Rail-to-Rail Output Range for Fully Differential Amplifiers to Include True Zero Volts, TIDU187
- Fully-Differential Amplifiers, SLOA054
- OPAx835 Ultra Low-Power, Rail-to-Rail Out, Negative Rail In, VFB Op Amp, SLOS713
- PCM4204 High-Performance 24-Bit, 216 kHz Sampling Four-Channel Audio Analog-to-Digital Converter, SBAS327
- SN74AVC1T45 Single-Bit Dual-Supply Bus Transceiver with Configurable Voltage Translation and 3-State Outputs, SCES530
- THS4531ADGKEVM Evaluation Module, SLOU356

10.3 Community Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

10.4 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

10.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

10.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(0)	(4)	(5)		(0)
THS4531ID	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	T4531
THS4531ID.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	T4531
THS4531IDGK	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	4531
THS4531IDGK.B	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	4531
THS4531IDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAUAG SN	Level-2-260C-1 YEAR	-40 to 125	4531
THS4531IDGKR.B	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	4531
THS4531IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	T4531
THS4531IDR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	T4531
THS4531IDRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	T4531
THS4531IDRG4.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	T4531
THS4531IRUNR	Active	Production	QFN (RUN) 10	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	4531
THS4531IRUNR.B	Active	Production	QFN (RUN) 10	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	4531
THS4531IRUNRG4	Active	Production	QFN (RUN) 10	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	4531
THS4531IRUNRG4.B	Active	Production	QFN (RUN) 10	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	4531
THS4531IRUNT	Active	Production	QFN (RUN) 10	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	4531
THS4531IRUNT.B	Active	Production	QFN (RUN) 10	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	4531

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.



PACKAGE OPTION ADDENDUM

17-Jun-2025

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
THS4531IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.25	3.35	1.25	8.0	12.0	Q1
THS4531IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
THS4531IDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
THS4531IRUNR	QFN	RUN	10	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
THS4531IRUNRG4	QFN	RUN	10	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
THS4531IRUNT	QFN	RUN	10	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2



PACKAGE MATERIALS INFORMATION

23-Jul-2025



All ulmensions are norminal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
THS4531IDGKR	VSSOP	DGK	8	2500	366.0	364.0	50.0
THS4531IDR	SOIC	D	8	2500	353.0	353.0	32.0
THS4531IDRG4	SOIC	D	8	2500	353.0	353.0	32.0
THS4531IRUNR	QFN	RUN	10	3000	213.0	191.0	35.0
THS4531IRUNRG4	QFN	RUN	10	3000	213.0	191.0	35.0
THS4531IRUNT	QFN	RUN	10	250	213.0	191.0	35.0

TEXAS INSTRUMENTS

www.ti.com

23-Jul-2025

TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
THS4531ID	D	SOIC	8	75	507	8	3940	4.32
THS4531ID.B	D	SOIC	8	75	507	8	3940	4.32
THS4531IDGK	DGK	VSSOP	8	80	330	6.55	500	2.88
THS4531IDGK.B	DGK	VSSOP	8	80	330	6.55	500	2.88

RUN 10

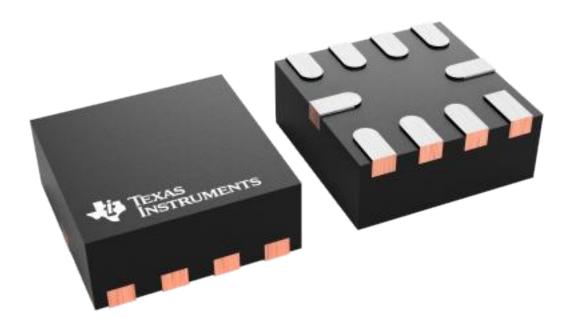
2 X 2, 0.5 mm pitch

GENERIC PACKAGE VIEW

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





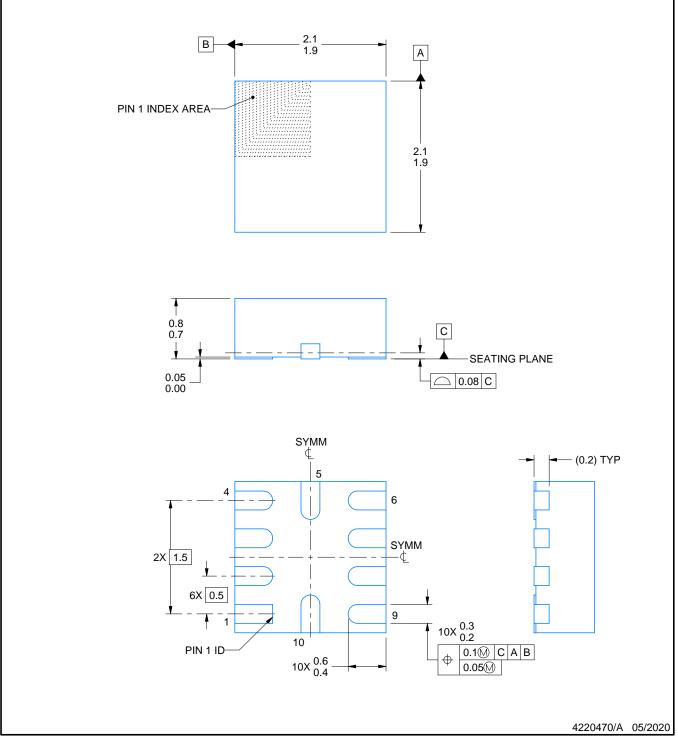
RUN0010A



PACKAGE OUTLINE

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.

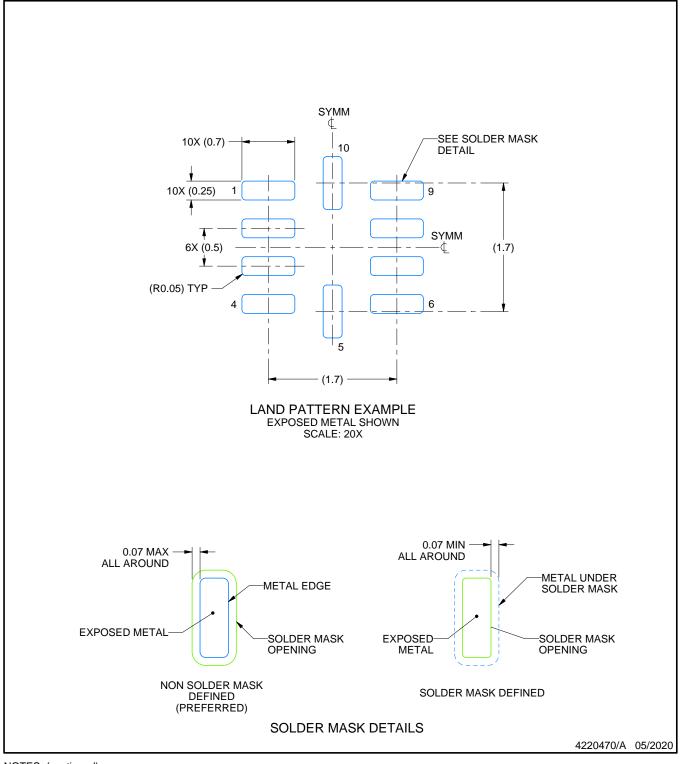


RUN0010A

EXAMPLE BOARD LAYOUT

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

3. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

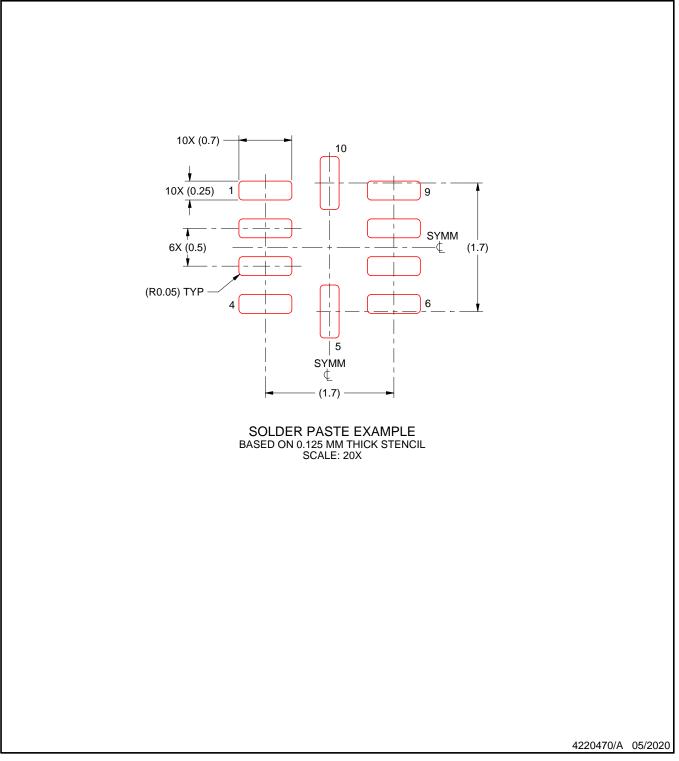


RUN0010A

EXAMPLE STENCIL DESIGN

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



D0008A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



D0008A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0008A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



DGK0008A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



DGK0008A

EXAMPLE BOARD LAYOUT

[™] VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown

on this view. It is recommended that vias under paste be filled, plugged or tented.

9. Size of metal pad may vary due to creepage requirement.



DGK0008A

EXAMPLE STENCIL DESIGN

[™] VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

12. Board assembly site may have different recommendations for stencil design.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025, Texas Instruments Incorporated